



ALPHA & OMEGA
SEMICONDUCTOR

AOC3870A

12V Common-Drain Dual N-Channel MOSFET

General Description

- Trench Power MOSFET technology
- Low $R_{SS(ON)}$
- With ESD protection to improve battery performance and safety
- Common drain configuration for design simplicity
- RoHS and Halogen-Free Compliant

Applications

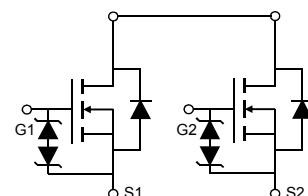
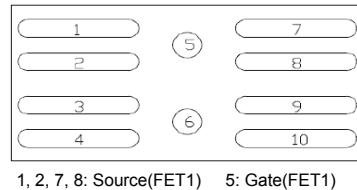
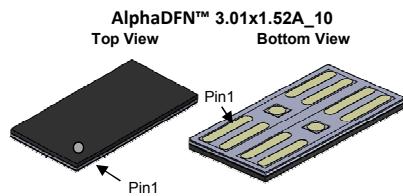
- Battery protection switch
- Mobile device battery charging and discharging

Product Summary

V_{SS}	12V
$R_{SS(ON)}$ (at $V_{GS}=4.5V$)	< 3.7mΩ
$R_{SS(ON)}$ (at $V_{GS}=4.0V$)	< 3.8mΩ
$R_{SS(ON)}$ (at $V_{GS}=3.8V$)	< 4mΩ
$R_{SS(ON)}$ (at $V_{GS}=3.1V$)	< 4.6mΩ
$R_{SS(ON)}$ (at $V_{GS}=2.5V$)	< 5.6mΩ

Typical ESD protection

HBM Class 2



Orderable Part Number

AOC3870A

Package Type

AlphaDFN 3.01x1.52A_10

Form

Tape & Reel

Minimum Order Quantity

8000

Absolute Maximum Ratings $T_A=25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Rating	Units
Source-Source Voltage	V_{SS}	12	V
Gate-Source Voltage	V_{GS}	± 8	V
Source Current(DC) ^{Note1}	I_S $T_A=25^\circ\text{C}$	22	A
Source Current(Pulse) ^{Note2}	I_{SM}	130	
Power Dissipation ^{Note1}	P_D $T_A=25^\circ\text{C}$	2.3	W
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Typical	Units
Maximum Junction-to-Ambient	$t \leq 10\text{s}$	45	°C/W
Maximum Junction-to-Ambient	Steady-State	55	°C/W

Note 1. I_S rated value is based on bare silicon. Mounted on 70mmx70mm FR-4 board.

Note 2. PW <10 μs pulses, duty cycle 1% max.

Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units	
STATIC PARAMETERS							
BV_{SSS}	Source-Source Breakdown Voltage	$I_S=250\mu\text{A}, V_{GS}=0\text{V}$	Test Circuit 6	12		V	
I_{SSS}	Zero Gate Voltage Source Current	$V_{SS}=12\text{V}, V_{GS}=0\text{V}$	Test Circuit 1		1	μA	
			$T_J=55^\circ\text{C}$		5		
I_{GSS}	Gate leakage current	$V_{SS}=0\text{V}, V_{GS}=\pm 8\text{V}$	Test Circuit 2		± 10	μA	
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{SS}=V_{GS}, I_S=250\mu\text{A}$	Test Circuit 3	0.4	0.7	1.1	V
$R_{SS(\text{ON})}$	Static Source to Source On-Resistance	$V_{GS}=4.5\text{V}, I_S=5\text{A}$	Test Circuit 4	2.1	2.95	3.7	$\text{m}\Omega$
		$T_J=125^\circ\text{C}$		2.9	4.05	5.0	
		$V_{GS}=4.0\text{V}, I_S=5\text{A}$	Test Circuit 4	2.2	3.05	3.8	$\text{m}\Omega$
		$V_{GS}=3.8\text{V}, I_S=5\text{A}$	Test Circuit 4	2.3	3.1	4.0	$\text{m}\Omega$
		$V_{GS}=3.1\text{V}, I_S=5\text{A}$	Test Circuit 4	2.4	3.4	4.6	$\text{m}\Omega$
g_{FS}	Forward Transconductance	$V_{SS}=5\text{V}, I_S=5\text{A}$	Test Circuit 4	2.8	3.9	5.6	$\text{m}\Omega$
			Test Circuit 3		50		
V_{FSS}	Forward Source to Source Voltage	$I_S=1\text{A}, V_{GS}=0\text{V}$	Test Circuit 5		0.57	1	V
DYNAMIC PARAMETERS							
R_g	Gate resistance	$f=1\text{MHz}$			1.2	$\text{k}\Omega$	
SWITCHING PARAMETERS							
Q_g	Total Gate Charge	$V_{G1S1}=4.5\text{V}, V_{SS}=6\text{V}, I_S=5\text{A}$		32		nC	
$t_{D(\text{on})}$	Turn-On DelayTime	$V_{G1S1}=4.5\text{V}, V_{SS}=6\text{V}, R_L=1.2\Omega,$ $R_{\text{GEN}}=3\Omega$	Test Circuit 8	1.2		μs	
t_r	Turn-On Rise Time			3.0		μs	
$t_{D(\text{off})}$	Turn-Off DelayTime			3.1		μs	
t_f	Turn-Off Fall Time			8.2		μs	

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TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

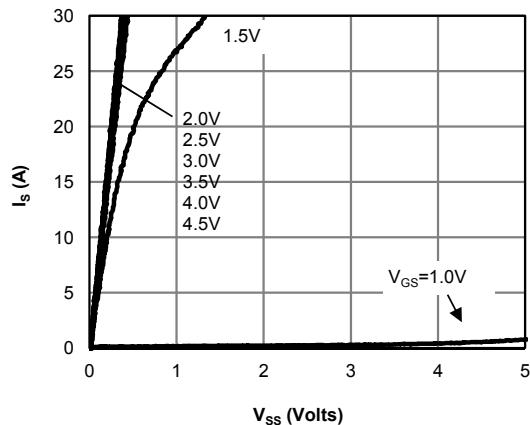


Figure 1: On-Region Characteristics

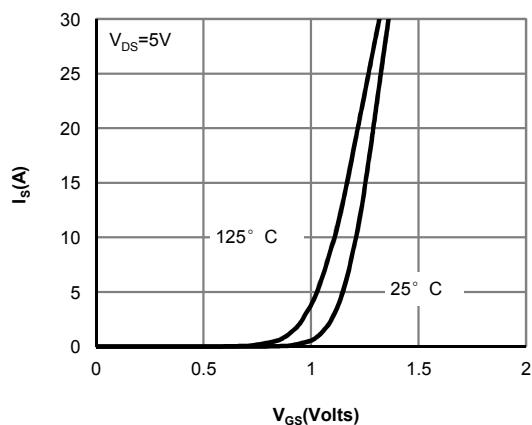


Figure 2: Transfer Characteristics

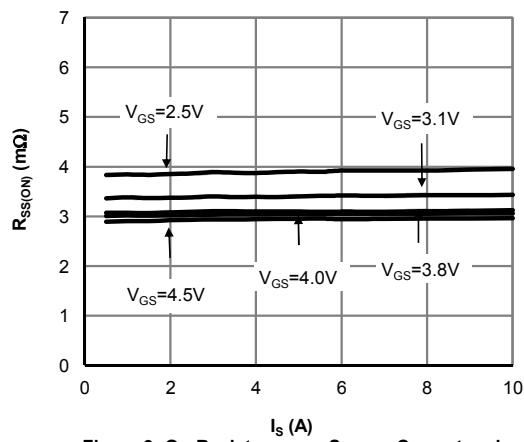


Figure 3: On-Resistance vs. Source Current and Gate Voltage

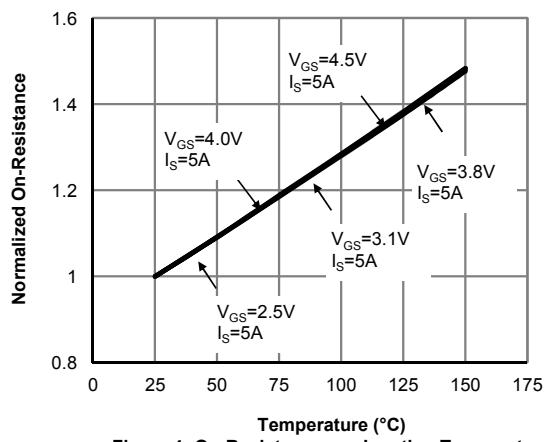


Figure 4: On-Resistance vs. Junction Temperature

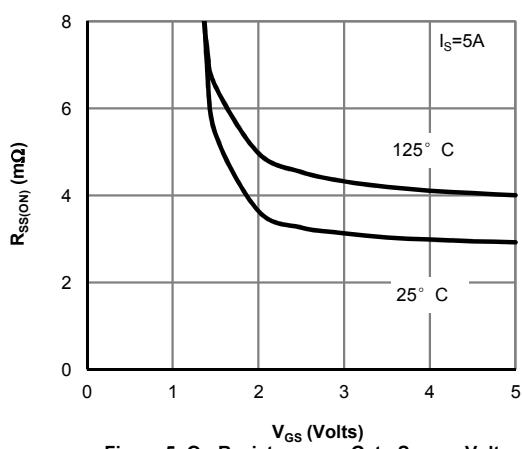


Figure 5: On-Resistance vs. Gate-Source Voltage

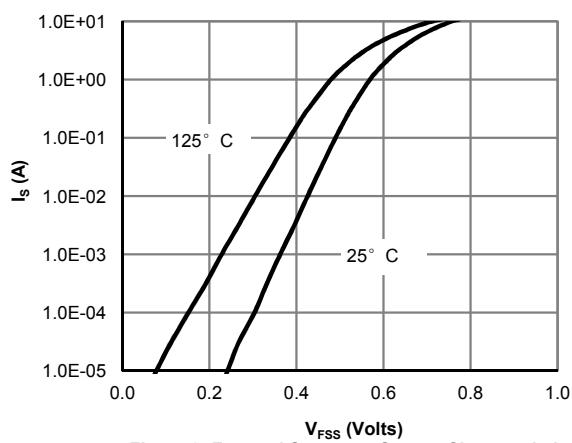


Figure 6: Forward Source to Source Characteristics



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

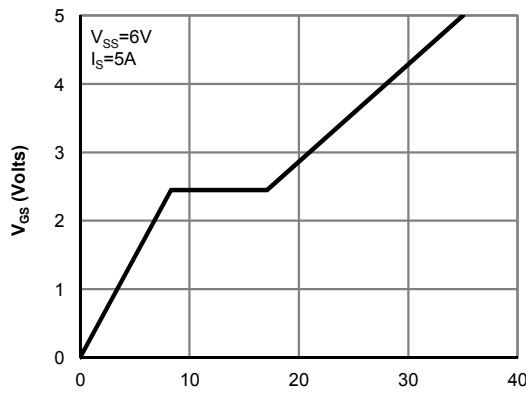


Figure 7: Gate-Charge Characteristics

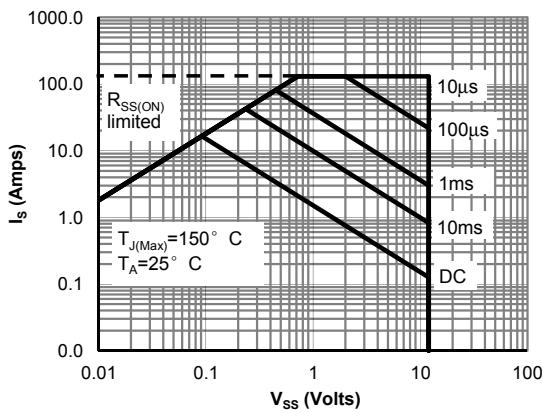


Figure 8: Maximum Forward Biased Safe Operating Area (Note1)

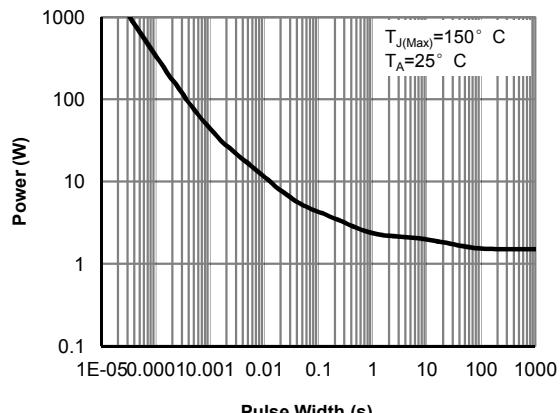


Figure 9: Single Pulse Power Rating Junction-to-Ambient (Note1)

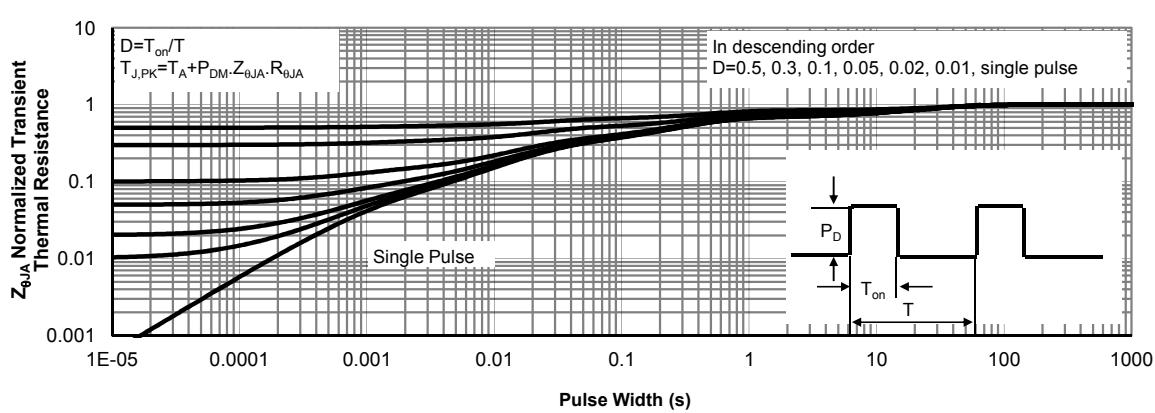
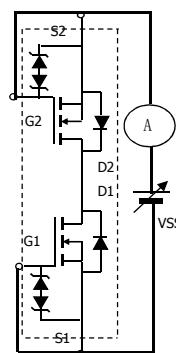


Figure 10: Normalized Maximum Transient Thermal Impedance (Note1)

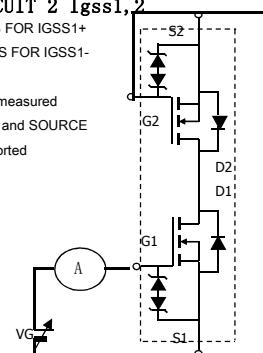


TEST CIRCUIT 1 I_{SSS}
POSITIVE V_{SS} FOR I_{SSS+}
NEGATIVE V_{SS} FOR I_{SSS-}



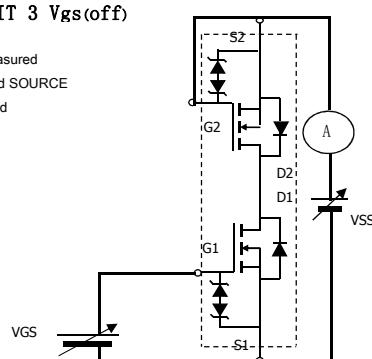
TEST CIRCUIT 2 $I_{GSS1,2}$
POSITIVE V_G FOR I_{GSS1+}
NEGATIVE V_G FOR I_{GSS1-}

When FET1 is measured
between GATE and SOURCE
of FET2 are shorted



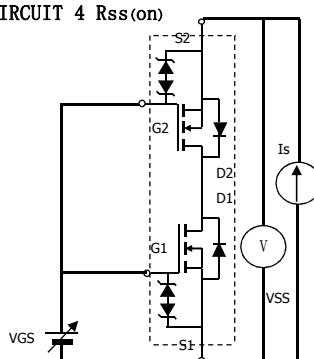
TEST CIRCUIT 3 $V_{GS(off)}$

When FET1 is measured
between GATE and SOURCE
of FET2 are shorted



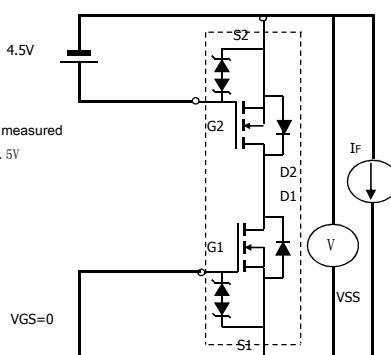
TEST CIRCUIT 4 $R_{SS(on)}$

V_{SS}/ I_S



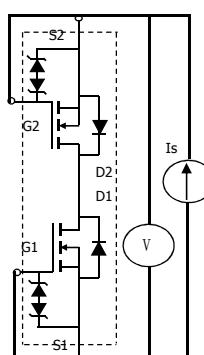
TEST CIRCUIT 5 $V_{F(ss),1,2}$

When FET1 measured
FET2 V_{GS}=4.5V



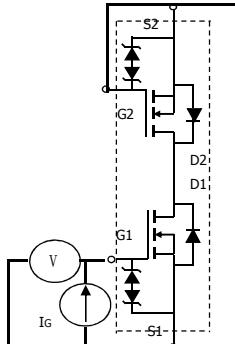
TEST CIRCUIT 6 BV_{DSS}

POSITIVE V_{SS} FOR I_{SSS+}
NEGATIVE V_{SS} FOR I_{SSS-}

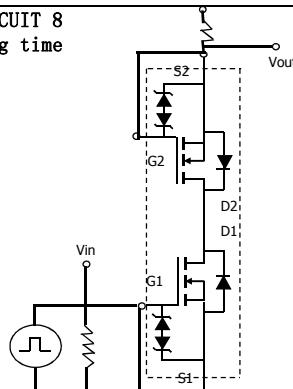


TEST CIRCUIT 7 $BV_{GS01,2}$
POSITIVE V_{SS} FOR I_{SSS+}
NEGATIVE V_{SS} FOR I_{SSS-}

When FET1 is measured
between GATE and SOURCE
of FET2 are shorted



**TEST CIRCUIT 8
Switching time**



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